Chapter I: Part III

I. Study of conductors

I.1. Conductor in electrostatic equilibrium:

- A conductor is a medium (materials or substances) in which there are free charges (positive or negative) that can be set in motion under the action of an electric field..
- A conductor is said to be in electrostatic equilibrium if no electrical charge is moving inside of this conductor.

 \Rightarrow The electrons are not subjected to any macroscopic force

I.2. Properties:

- ✓ The electric field is zero inside an equilibrium conductor $(\vec{E} = \vec{0})$
- ✓ A conductor in equilibrium constitutes an equipotential volume $(\vec{E} = \vec{0} \implies V = cts)$
- $\checkmark\,$ The total charge is zero in any internal region of an equilibrium conductor.

$$\vec{E} = \vec{0} \Longrightarrow \phi = \oint_{(S)} \vec{E}(M) \cdot d\vec{S} = \frac{\sum q_i}{\varepsilon_0} = 0 \Longrightarrow \sum q_i = 0$$

✓ The injected charges are located on the external surface



- ✓ The field on the surface is perpendicular to this surface (Just outside a conductor, the electric field lines are perpendicular to its surface).
- ✓ The same properties are valid for a hollow conductor.
- \Rightarrow The injected charges are located on the external surface.



✓ When we connect a charged conductor to another conductor, there will be an exchange of charges between the two in such a way that at the end of the transport, the two conductors constitutes the same equipotential volume.



- I.3. Electric field near the surface of a conductor (Just outside): Coulomb's theorem.
- > At a point infinitely close to the surface(S), The field \vec{E} is normal to (S).
- e): $d\vec{S}_{Lat}$ $\vec{E} = \vec{0}$ $d\vec{S}_{int}$ (S)
- > To find the field \vec{E} at this point, we apply Gauss's theorem:
 - ✓ The chosen Gaussian surface is a flattened cylinder, with one base located outside the surface and the other base at a depth such that the surface charge is completely inside the cylinder.
 - ✓ Applying Gauss's theorem to this closed surface, we get:

$$\phi = \oint_{(S)} \vec{E}(M) \cdot d\vec{S} = \oint_{(S)} \vec{E}(M) \cdot d\vec{S}_{ext} + \oint_{(M)} \vec{E}(M) \cdot d\vec{S}_{int} + \oint_{(M)} \vec{E}(M) \cdot d\vec{S}_{Lat}$$
$$= E(M) \cdot S_{ext} = \frac{\sum q_i}{\varepsilon_0} = \frac{\sigma S_{ext}}{\varepsilon_0} \implies E(M) = \frac{\sigma}{\varepsilon_0}$$

Théorème: The electrostatic field just outside (near) a conductor carrying a charge with

a surface charge density σ is: $\vec{E} = \frac{\sigma}{\epsilon_0} \vec{u}_n$

Remarks:

- At the crossing of the surface of a conductor, by continuity, the Field varies from 0 (inside) to $\frac{\sigma}{\varepsilon_0}$ (outside) through the value $\frac{\sigma}{2\varepsilon_0}$ on the real surface of the conductor.
- This last expression of the field will be used for the calculation of the electrostatic pressure.

I.4. Electrostatic pressure:

Let « dS » a surface element carrying a charge dq with

 $dq = \sigma dS$

The field
$$\vec{E} = \frac{\sigma}{2\varepsilon_0}\vec{u}$$
 exerts, on the charge, a force: $d\vec{F} = dq \vec{E} = \sigma dS \frac{\sigma}{2\varepsilon_0}\vec{u} = \frac{\sigma^2}{2\varepsilon_0}dS\vec{u}$

Electrostatic pressure is given by: $P_e = \frac{d\vec{F}}{d\vec{S}} = \frac{\sigma^2}{2\varepsilon_0}$



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I.5. Power ot the pointed conductors:

□ Considering Two Conductive Spheres with radius R_1 and R_2 ($R_1 < R_2$), connected by a long conducting wire.

□ The two spheres are brought to the same potential:

$$V_1 = V_2 \Longrightarrow \frac{kq_1}{R_1} = \frac{kq_2}{R_2} \Longrightarrow \frac{\sigma_1 S_1}{R_1} = \frac{\sigma_2 S_2}{R_2}$$



$$\Rightarrow \frac{\sigma_1 4\pi R_1^2}{R_1} = \frac{\sigma_2 4\pi R_2^2}{R_2} \Rightarrow \frac{\sigma_1}{R_2} = \frac{\sigma_2}{R_1} \implies \sigma_1 R_1 = \sigma_2 R_2$$

The sphere with the smallest radius carries the greatest density of charges.

➤ A tip (R very small) carries a large charge density.



A very pointed conductor has a large charge concentration at the point. The electric field is very strong at the point and can exert a force large enough to transfer charge on or off the conductor.



Lightning rods are used to prevent the buildup of large excess charges on structures and, thus, are pointed.

I.6. <u>Capacity of a conductor</u>:

Consider an insulated conductor in electrostatic equilibrium carrying a charge Q distributed over its outer surface with Surface charge density σ such as:

$$Q = \iint \sigma dS$$

If the charge Q increases, the density σ increases proportionally: $\sigma = aQ$

The potential created by *Q* at a point M in space:

$$V = k \iint \frac{\sigma dS}{r} = kQ \iint \frac{adS}{r}$$

We deduce that the ratio between the charge and the potential to which the conductor is

brought, given by $C = \frac{Q}{V}$ depends only on the geometry of the conductor, it is called <u>the conductor's own capacity</u>.

$$[C] = Farad$$

Example: Find the own capacity of a sphere of radius R carrying a charge Q uniformly distributed over its surface.

✤ At a point M on the surface of the sphere, the potential is given by:

$$V = \frac{kQ}{R} = \frac{Q}{4\pi\varepsilon_0 R} \quad ; \quad C = \frac{Q}{V} = \frac{Q}{\frac{Q}{4\pi\varepsilon_0 R}} = 4\pi\varepsilon_0 R$$

I.7. <u>Potential (Internal) energy of an isolated charged conductor</u>:

- To bring a charge Q to a conductor, initially neutral, it is necessary to provide a work "W"
- > The variation of potential energy undergone by an elementary charge dq, brought back from infinity (chosen as a reference of potential) to the conductor:

$$dE_P = Vdq$$
 With $V = \frac{q}{c}$

> The potential energy of the conductor when it reaches its full charge q is:

$$E_{P} = \int_{0}^{q} V dq = \int_{0}^{q} \frac{q}{C} dq \implies E_{P} = \frac{1}{2} \frac{q^{2}}{C} = \frac{1}{2} \frac{qV}{C} = \frac{1}{2} \frac$$

- I.8. Phenomenon of influence between electrical conductors:
 - ▶ An electrical conductor is said to be neutral if $\sum q_{int} = 0$ ($\sum q^+ + \sum q^- = 0$)
 - > A neutral conductor placed in an electric field polarizes.

Partial influence:

- \Box Let be a neutral conductor placed in a field \vec{E}_{ext}
- Negative charges move in the opposite direction of the field.
- □ On either side of the conductor appear positive and negative

charges in equal quantities.

- □ A new field \vec{E}_i , due to this distribution of charges, is created and comes to superimpose the field \vec{E}_{ext} .
- \Box Inside the conductor, the charges do not stop moving until the field $\vec{E}_i = -\vec{E}_{ext}$
 - \Rightarrow The conductor is again in equilibrium in a polarized state
- □ The charge is not varied, there has been a modification in the distribution of the charge.









If the conductor is kept at a constant potential (e.g. zero):



□ The ground and conductor (A) form a single conductor.

- □ The potential of the conductor (A) becomes zero.
- □ The positive charges are pushed back into the ground and the negative charges remain trapped by the field created by the body (B).
- □ There is no field line leaving the conductor (A).



- > The influencing charge is distributed on the conductor (B).
- There is a feedback influence of (A) on (B)

 \Rightarrow We say that there is mutual influence

Total Influence:

- \Box Let (B) a conductor carries a charge $q_B > 0$ and (A) A hollow conductor in equilibrum
- □ We speak of total influence when all field lines starting from (B) end up at (A).

□ After the influence, a charge $q_{A_{int}}$ negative appears on the internal surface of (A) and a positive charge $q_{A_{ext}}$ on the external surface

Let's choose the surface(Σ) passing inside (A) and we apply Gauss's theorem:

$$\phi = \iint \vec{E} \cdot d\vec{S} = \frac{\sum q_i}{\varepsilon_0} = 0 \ (car \ E = 0) \Longrightarrow q_i = q_B + q_{A_{int}} = 0$$
$$\implies q_B = -q_{A_{int}}$$

□ If (A) and isolated and neutral initially, there will be:

□ If (A) and isolated and initially carries a charge q_0 , There will be: $q_B = -q_{A_{int}} = q_{A_{ext}} + q_0$

$$+ q_{A_{int}} = 0$$

$$q_{A_{ext}} = -q_{A_{int}} = q_B$$

I.8. Capacitors:

 \Box Let a conductor (B) be held at a potential $V_B > 0$ carries a charge : $q_B = CV_B$

□ Let a conductor (A) be held at zero potential (V=0) $V_B > 0$

□ The influence of (B) leads to the appearance of negative charges on (A).

□ These negative charges of (A) in turn influence (B) on which new charges appear from the generator in order to keep V_B constant.

 $V_A = 0$

 \Box There is condensation of charges on (B) and its capacity is given by: $C = \frac{Q}{V}$

□ Conductors (A) and (B) form a capacitor represented by: A = A

 \Box We call $|q_A| = |q_B| = q$: Capacitor charge

 \Box "C" depends only on the shape of the conductor and the nature of the air between them

□ If the two conductors are brought closer together, the capacity becomes greater.

Method of calculating the capacitance of a capacitor:

- 1- Calculate the electric field at any point inside the capacitor.
- 2- Deduct the potential difference ΔV between the two conductors.

3- effect the report :
$$\frac{Q}{\Delta V} = C$$

Examples:

<u>1- Plane capacitor:</u>

Formed by two infinite parallel conductive planes, separated by a distance "e".

- ✓ Field created by (A) : $E_A = \sigma/2\varepsilon_0$
- ✓ Field created by (B) : $E_B = \sigma/2\varepsilon_0$

 \implies Field created between (A) and (B): $E = E_A + E_B = \sigma/\varepsilon_0$

$$\checkmark \int_{V_A}^{V_B} dV = -\int_0^e E dr \implies V_B - V_A = -\frac{\sigma}{\varepsilon_0} e \implies V_A - V_B = \frac{\sigma}{\varepsilon_0} e$$
$$\checkmark C = \frac{Q}{V_A - V_B} = \frac{\sigma S \varepsilon_0}{\sigma e} \implies C = \frac{S \varepsilon_0}{e}$$



2- Cylindrical capacitor:

The field created between the two cylinders:

Gauss's theorem:
$$\phi = \iint \vec{E} \cdot d\vec{S} = \frac{\sum q_i}{\varepsilon_0}$$

$$\iint \vec{E} \cdot d\vec{S} = \iint \vec{E} \cdot d\vec{S_1} + \iint \vec{E} \cdot d\vec{S_2} = \iint \vec{E} \cdot dS_1 = E \cdot 2\pi rL$$
$$\Rightarrow E \cdot 2\pi rL = \frac{Q}{\varepsilon_0} \qquad \Rightarrow E = \frac{Q}{2\pi\varepsilon_0 rL}$$



The difference in potential between the two cylinders:

$$\int_{V_1}^{V_2} dV = -\int_{R_1}^{R_2} E dr \implies V_2 - V_1 = -\frac{Q}{2\pi\varepsilon_0 L} ln \frac{R_2}{R_1} \implies V_1 - V_2 = \frac{Q}{2\pi\varepsilon_0 L} ln \frac{R_2}{R_1}$$

$$\Rightarrow Capacitance: \quad C = \frac{Q}{V_1 - V_2} = \frac{2\pi\varepsilon_0 L}{ln R_2/R_1}$$

3- Spherical capacitor:

The field created between the two spheres:

Using Gauss's theorem, we find:

$$E = \frac{Q}{4\pi\varepsilon_0 r^2}$$



The potential between the two spheres:

We find:

$$V_1 - V_2 = \frac{Q}{4\pi\varepsilon_0} \left(\frac{R_2 - R_1}{R_1 R_2}\right)$$

$$\succ \text{ Capacitance:} \quad C = \frac{Q}{V_1 - V_2} \quad = \frac{4\pi\varepsilon_0 R_1 R_2}{R_2 - R_1}$$

Potential energy of a capacitor (stored in a capacitor):

□ Let be a capacitor with a capacitance "C" formed by two armatures A and B

$$\checkmark E_P = E_{P_A} + E_{P_B} = \frac{1}{2}Q_A V_A + \frac{1}{2}Q_B V_B$$

$$\checkmark Q_A = -Q_B = Q \implies E_P = \frac{1}{2}Q(V_A - V_B)$$

$$A = -Q_B = Q \implies E_P = \frac{1}{2}Q(V_A - V_B)$$

Knowing that:
$$C = \frac{Q}{V_A - V_B} \implies E_P = \frac{1}{2}Q(V_A - V_B) = \frac{1}{2}C(V_A - V_B)^2 = \frac{1}{2}\frac{Q}{C}$$

 \Box In general, for a set of capacitors carrying charges Q_i under different potentials V_i :

$$E_P = \frac{1}{2} Q_i V_i$$

Capacitor Association



$$\Rightarrow C_{eq}(V_A - V_B) = C_1(V_A - V_B) + C_2(V_A - V_B) + \dots + C_n(V_A - V_B)$$
$$\Rightarrow C_{eq} = C_1 + C_2 + \dots + C_n \quad \Rightarrow C_{eq} = \sum_{i=1}^n C_i$$

<u>1- Series Association :</u>



All capacitors carry the same charge Q:

 $V_{A} - V_{B} = (V_{A} - V_{M}) + (V_{M} - V_{N}) + \dots + (V_{P} - V_{B})$ $\Rightarrow \frac{Q}{C_{eq}} = \frac{Q}{C_{1}} + \frac{Q}{C_{2}} + \dots + \frac{Q}{C_{n}} \Rightarrow \frac{1}{C_{eq}} = \frac{1}{C_{1}} + \frac{1}{C_{2}} + \dots + \frac{1}{C_{n}}$ $\Rightarrow \frac{1}{C_{eq}} = \sum_{i=1}^{n} \frac{1}{C_{i}}$